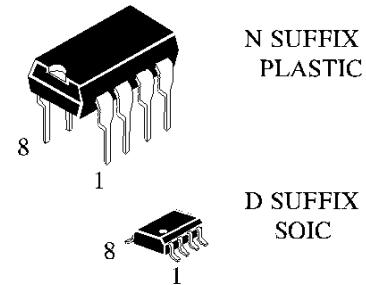


Low Power Dual Operational Amplifier

The HT358A contains two independent high gain operational amplifiers with internal frequency compensation. The op-amps operate over a wide voltage range. The low power drain makes the HT358A a good choice for battery operation.

- Internally frequency compensated for unity gain
- Large DC voltage gain
- Single or Split Supply Operation
- Input common-mode voltage range to ground
- Large output voltage swing: 0V DC to V_{CC}-1.5V DC
- Power drain suitable for battery operation
- Low input offset voltage and offset current
- Differential input voltage range equal to the power supply voltage



ORDERING INFORMATION

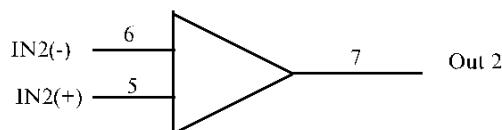
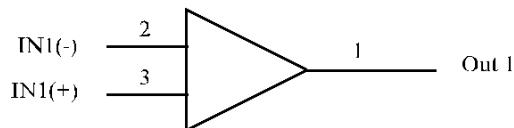
HT358AN Plastic

HT358AR SOIC

HT358AG Chip

 $T_A = 0^\circ \text{ to } 70^\circ \text{ C}$ for all packages

BLOCK DIAGRAM



PIN 4 = GND

 PIN 8=V_{CC}

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Power Supply Voltages		
	Single Supply	32	V
	Split Supplies	±16	
V _{IDR}	Input Differential Voltage Range (1)	±32	V
V _{ICR}	Input Common Mode Voltage Range	-0.3 to 32	V
t _S	Short-Circuit duration of Output	100	ms
I _{IN}	Input Current, per pin (2)	50	mA
T _J	Junction Temperature Plastic Packages	150	°C
T _{STG}	Storage Temperature Plastic Packages	-55 to +125	°C
T _L	Lead Temperature, 1mm from Case for 10 Seconds	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.
 Functional operation should be restricted to the Recommended Operating Conditions.

Notes:

1. Split Power Supplies.
2. V_{IN}<-0.3V

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	±2.5 or 5.0	±15 or 30	V
T _A	Operating Temperature, All Package Types	0	+70	°C

DC ELECTRICAL CHARACTERISTICS ($T_A=0 \div +70^\circ C$)

Symbol	Parameter	Test Conditions	Guaranteed Limit		Unit
			Min	Max	
V_{IO}	Maximum Input Offset Voltage	$V_{CC}=5.0\text{-}30V$, $R_S=0\Omega$, $V_O=1.4V$ $V_{ICR}=0V \text{ } -(V_{CC}-1.5V)^*$ $V_{ICR}=0V \text{ } -(V_{CC}-2.0V)$	1	5.0* 7.0	mV
I_{IO}	Maximum Input Offset Current	$V_{CC}=5.0\text{-}30V$, $V_O=1.4V$		$\pm 50^*$ ± 150	nA
I_{IB}	Maximum Input Bias Current	$V_{CC}=5.0\text{-}30V$, $V_O=1.4V$		-250* -500	nA
V_{ICR}	Input Common Mode Voltage Range	$V_{CC}=30V$	0 0	$V_{CC}-1.5V^*$ $V_{CC}-2.0V$	V
I_{CC}	Maximum Power Supply Current	$R_L=\infty$, $V_{CC}=30V$, $V_0=15V$ $R_L=\infty$, $V_{CC}=5V$, $V_0=2.5V$		2 1.2	mA
A_{VOL}	Minimum Large Signal Open-Loop Voltage Gain	$V_{CC}=15V$, $R_L=2K\Omega$	25* 15		V/mV
V_{OH}	Minimum Output High-Level Voltage Swing	$V_{CC}=5V$, $R_L=2K\Omega^*$ $V_{CC}=30V$, $R_L=2K\Omega$ $V_{CC}=30V$, $R_L=10K\Omega$	3.3* 26 27		V
V_{OL}	Maximum Output Low-Level Voltage Swing	$V_{CC}=5V$, $R_L=10K\Omega$		20	mV
CMR	Common Mode Rejection	Ω $V_{CC}=5\text{-}30V$, $R_S=10K$	65*		dB
PSR	Power Supply Rejection	$V_{CC}=5\text{-}30V$	65*		dB
I_{SC}	Maximum Output Short Circuit to GND	$V_{CC}=5.0V$, $V_O=0V$		60*	mA
I_{O+}	Minimum Source Output Current	$V_{CC}=15V$, $V_{ID}=1.0V$	20*		mA
I_{O-}	Minimum Output Sink Current	$V_{CC}=15V$, $V_O=15V$, $V_{ID}=-1.0V$ $V_{CC}=15V$, $V_O=0.2V$, $V_{ID}=-1.0V$	10* 12*		mA $\propto A$
V_{IDR}	Differential Input Voltage Range	All $V_{IN} \geq GND$ or V-Supply (if used)		V_{CC}^*	V

 * $T_A = +25^\circ C$

NOTE: Guaranteed Limits of DC Electrical Characteristics are given for $T_A=0$, $+70^\circ C$ as the information for chips

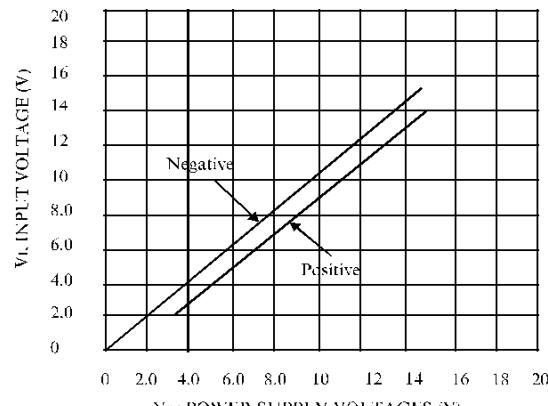
TYPICAL PERFORMANCE CHARACTERISTICS ($T_A = +25^\circ\text{C}$)

Figure 1. Input Voltage Range

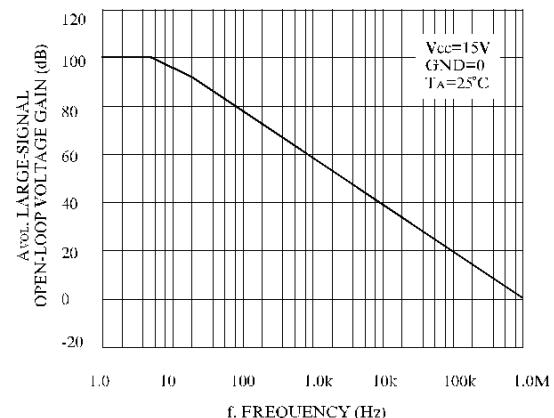


Figure 2. Open-Loop Frequency

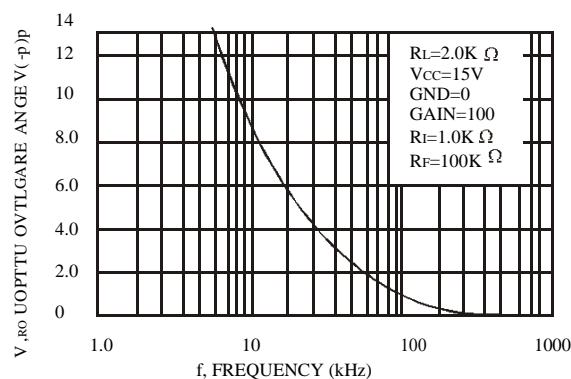


Figure 3. Large-Signal Frequency Response

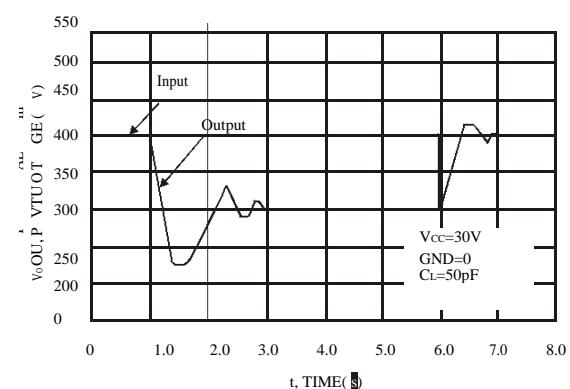


Figure 4. Small-Signal Voltage Follower Pulse Response (Noninverting)

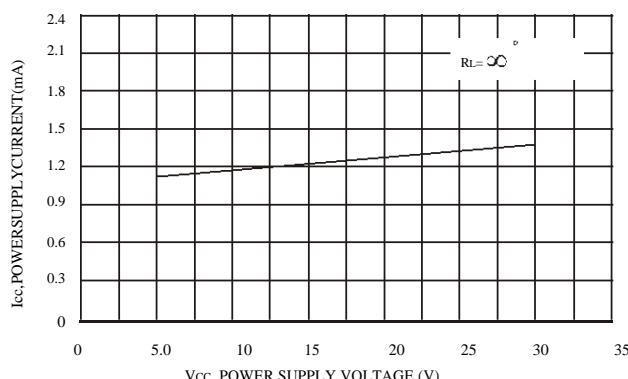


Figure 5. Power Supply Current versus Power Supply Voltage

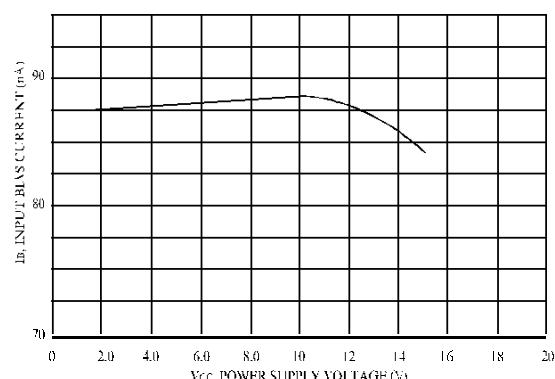
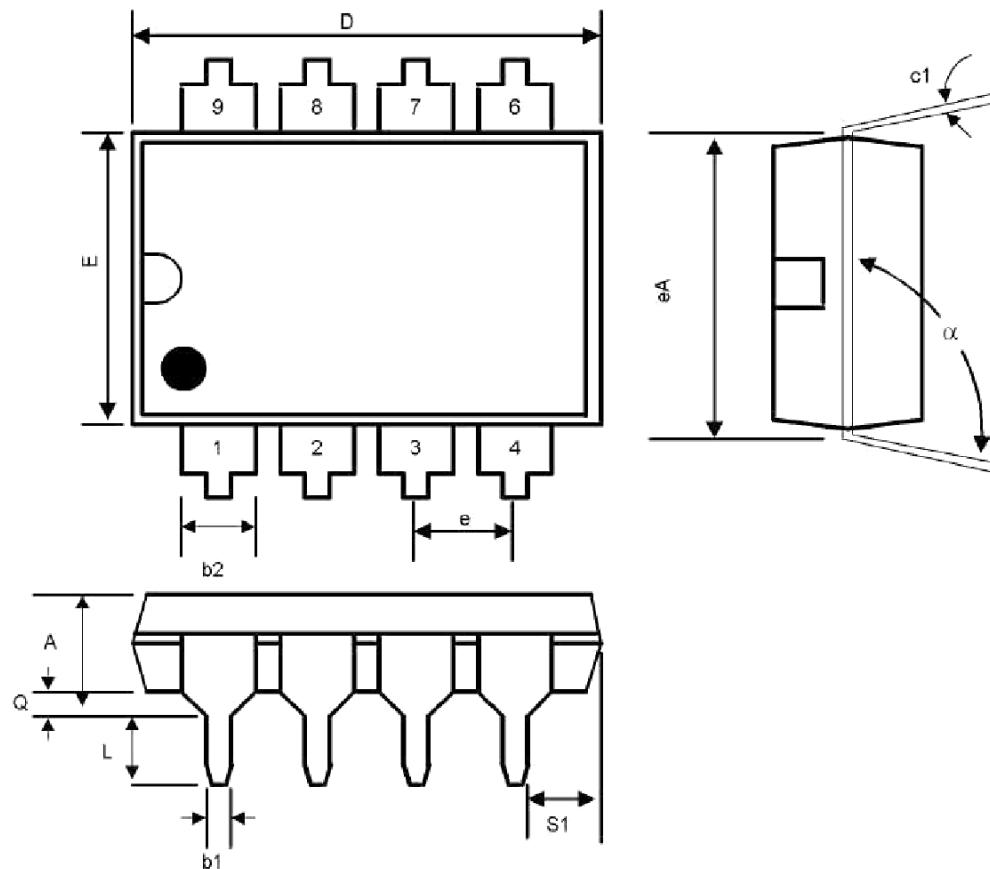
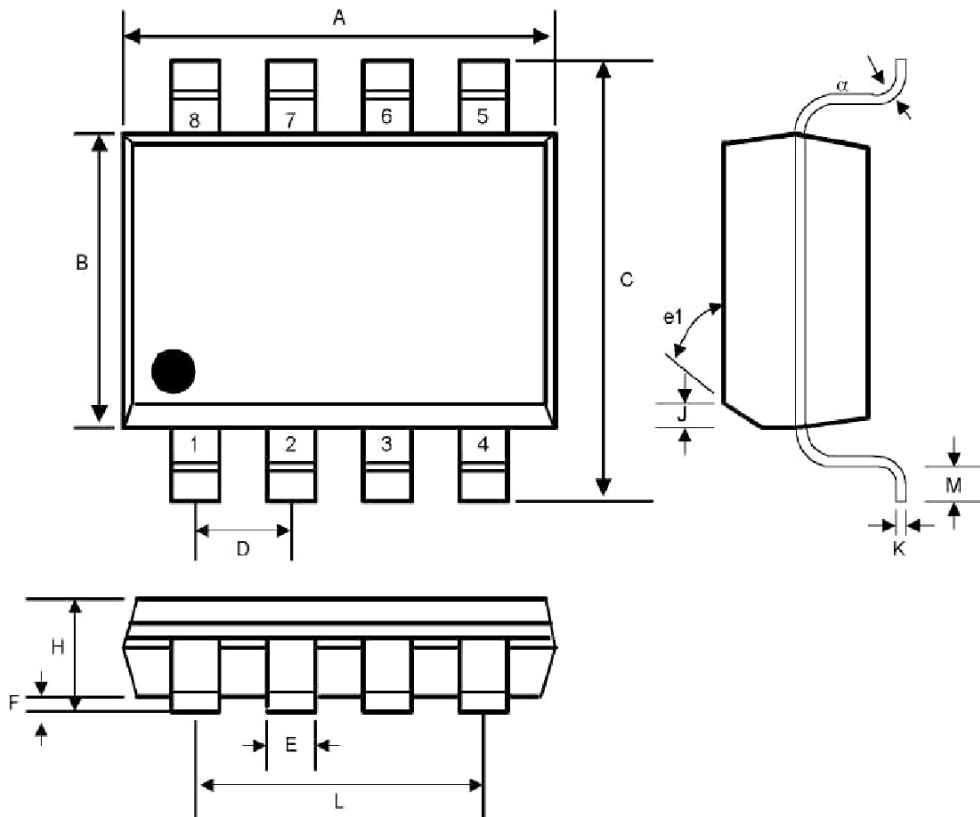


Figure 6. Input Bias Current versus Power Supply Voltage

Package Outlines: DIP-8


SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.200	-	5.08	-
b1	0.014	0.023	0.36	0.58	-
b2	0.045	0.065	1.14	1.65	-
c1	0.008	0.015	0.20	0.38	-
D	0.355	0.400	9.02	10.16	-
E	0.220	0.310	5.59	7.87	-
e	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
L	0.125	0.200	3.18	5.08	-
Q	0.015	0.060	0.38	1.52	-
s1	0.005	-	0.13	-	-
alpha	90°	105°	90°	105°	-

Small Outline SOP-8


SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.188	0.197	4.80	5.00	-
B	0.149	0.158	3.80	4.00	-
C	0.228	0.244	5.80	6.20	-
D	0.050	BSC	1.27	BSC	-
E	0.013	0.020	0.33	0.51	-
F	0.004	0.010	0.10	0.25	-
H	0.053	0.069	1.35	1.75	-
J	0.011	0.019	0.28	0.48	
K	0.007	0.010	0.19	0.25	-
M	0.016	0.050	0.40	1.27	
L	0.150	REF	3.81	REF	-
e_1	45°		45°		-
α	0°	8°	0°	8°	-

*All specs and applications shown above subject to change without prior notice.

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